

mately 2. Experimentally we have found that R has the value of unity or slightly greater, within a maximum experimental error of ±0.2. There is no significant variation in this value between focused and unfocused input beams, so spatial non-overlap cannot be a factor. Pulse envelope traces (Tektronix 519 oscilloscope) of the laser output show regular modulation indicating some locking of the multimodes. While this would increase the efficiency of S.H.G.,¹² it would require for the mixing process a more critical synchronization of the resulting modulation of the two fundamental frequencies. Streak interferograms (2 nsec resolution) show that such complete synchronization does not exist.

After this work had been completed, the mixing of ruby and neodymium Q-switched lasers operating in a common resonator to produce a summed output at 4192 Å was reported¹³ but the relative efficiencies of S.H.G. and sum generation were not compared.

A NEW PHOSPHOR FOR FLYING-SPOT CATHODE-RAY TUBES FOR COLOR TELEVISION: YELLOW-EMITTING $Y_3Al_5O_{12}-Ce^{3+}$

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The fluorescence of $Y_3Al_5O_{12}-Ce^{3+}$ under cathode-ray excitation consists of an emission band peaking at 550 nm. The decay time is 0.07-0.08 μ sec. In view of these properties this phosphor is very suitable for flying-spot cathode-ray tubes for color television.

Ce³⁺-activated phosphors are usually characterized by an emission band with a maximum in or near the uv region and a very short decay time.¹ In this Letter we report on a Ce³⁺-activated phosphor with an emission at considerably longer wavelengths, viz. $Y_3Al_5O_{12}$ —Ce.

Samples with the general formula $Y_{3-x}Ce_xAl_5O_{12}$ (x < 0.3) were prepared by firing intimate mixtures of high-purity Y_2O_3 , hydrated alumina and Ce_2O_3 at 1500° in nitrogen. X-ray analysis showed them to be pure garnets. According to chemical analysis the Ce^{4+} content of the samples is negligible. This was also the case if the samples were fired in oxygen, air, or nitrogen containing 5% of hydrogen. Optical measurements were performed as described previously.²

Y₃Al₅O₁₂-Ce shows a bright yellow emission

under excitation with cathode rays as well as with blue radiation. Figure 1 shows the spectral energy

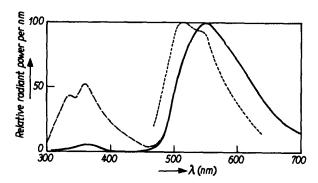


Fig. 1. Spectral energy distribution of $Y_{2,94}Ce_{0,06}Al_5O_{12}$ under cathode ray excitation (full line), uv excitation (broken line) and of $Y_{2,94}Ce_{0,06}Al_2Ga_3O_{12}$ under uv excitation (dotted line). The solid and broken lines coincide in the visible region.



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distribution of the emission of $Y_3Al_5O_{12}$ —Ce under cathode-ray (cr) as well as under ultraviolet (uv) excitation. Figure 2 shows the excitation spectrum of the visible fluorescence of $Y_3Al_5O_{12}$ —Ce and the diffuse reflection spectra of $Y_3Al_5O_{12}$ —Ce and unactivated $Y_3Al_5O_{12}$. The radiant efficiency for cr excitation (20 keV) is 3.5% for the emission in the visible region and 0.1% for the emission in the uv region.³ These figures were found for a sample with composition $Y_{2.94}Ce_{0.06}Al_5O_{12}$ and vary only slightly with the Ce concentration. At very low Ce concentration the ratio of the intensities of uv to visible emission increases.

Decay times were measured with cr and uv excitation. With cr excitation the phosphor was irradiated with short electron beam pulses (duration 0.1 μ sec, repetition rate 10^4 cps) in a demountable tube. The fluorescence was collected on a photomultiplier and displayed on an oscilloscope. The decay time was found to be shorter than 0.1 μ sec. The phosphor was also excited by a short pulse of uv radiation with the aid of a TRW nanosecond spectral source system (duration 0.004 μ sec, repetition rate 5×10^3 cps). The output was again displayed on an oscilloscope. The decay time proved to be 0.07–0.08 μ sec.

All Ce³⁺-activated phosphors described in the literature show the maximum of their emission in the uv or blue (up to \approx 410 nm). The emission from $Y_3Al_5O_{12}$ –Ce under cr excitation, however, lies almost entirely in the visible with a broad band peaking at 550 nm. There is also a uv emission band under short-wave uv excitation. In view of this peculiar behavior it may be wondered whether this emission is really due to the Ce³⁺ center. There are several reasons for believing that this is the case:

(a) Chemical analysis excludes other oxidation states of cerium; (b) unactivated Y₃Al₅O₁₂ does not

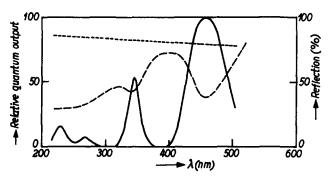


Fig. 2. Relative excitation spectrum of the visible fluorescence of Y_{2.94}Ce_{0.06}Al₅O₁₂ (solid line) and diffuse reflection spectra of Y_{2.94}Ce_{0.06}Al₅O₁₂ (broken line) and Y₃Al₅O₁₂ (dotted line).

emit in this region; (c) the decay time of Ce^{3+} phosphors is always very short, viz. shorter than 0.1 μ sec, since an allowed transition is involved ($^2D \rightarrow ^2F$). $Y_3Al_5O_{12}$ –Ce has such a short decay time; (d) the emission band of Ce^{3+} phosphors should consist of two bands, the ground state being split ($^2F_{7/2}$, $^2F_{5/2}$). The energy difference between these two bands is some 2000 cm⁻¹. Particularly at higher Ce concentrations this splitting is not always observed. The uv emission band of $Y_3Al_5O_{12}$ –Ce does indeed exhibit two peaks (29.800 and 27.800 cm⁻¹) but the visible band does not. $Y_3Al_2Ga_3O_{12}$ –Ce with similar but less efficient fluorescence, however, shows an indication of the splitting of this emission band in the visible.

Figure 2 shows that $Y_3Al_5O_{12}$ —Ce is most efficiently excited by 460 nm radiation. The efficiency for long-wave uv excitation is less, and that for short-wave uv excitation may even be termed low. The excitation bands correspond to absorption in the Ce³⁺ center. This follows from a comparison between the diffuse reflection spectra of $Y_3Al_5O_{12}$ and $Y_3Al_5O_{12}$ —Ce. These bands show the complete crystal field splitting of the 2D level of Ce³⁺.

Elsewhere we will discuss this and other Ce³⁺ phosphors more extensively. For the moment we conclude that Y₃Al₅O₁₂-Ce³⁺ is an exceptional Ce³⁺ phosphor with an emission at relatively long wavelengths and a high efficiency under cr excitation.

Therefore this phosphor can be of use for flyingspot cathode-ray tubes, especially for color television. When the screen of such a tube is scanned with a normal television raster, a decay time of the phosphor shorter than $\approx 0.1 \mu \text{sec}$ is required. Usually ZnO-Zn is used with an emission band at 500 nm containing only a small amount of red and with an efficiency which is about the same as that of Ce3+-activated phosphors. Its decay time, however, is too long, viz. $\approx 1 \mu \text{sec.}$ Therefore a large correction is applied to the output signal by electrical compensation with unavoidably a great reduction in this signal. Y₃Al₅O₁₂-Ce has a much higher output in the red region and, moreover, a much shorter decay time. Therefore the output signal of this tube is expected to be an order of magnitude higher than for ZnO-Zn. The emission of Y₃Al₅O₁₂-Ce does not contain blue. However, efficient blue phosphors with short decay time are available (for example, Ca₂Al₂SiO₇—Ce (ref. 1)), so that a mixture of these two phosphors will suffice.



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³For comparison: the most efficient Ce³⁺-activated phosphor Ca₂Al₂SiO₇ has an efficiency of 4% (ref. 1).

HIGH TEMPERATURE RESONANCE LOSSES IN SILICON-DOPED YTTRIUM-IRON GARNET (YIG)*

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The ferrimagnetic resonance linewidth of silicon-doped YIG, measured as a function of temperature at 13.4 kMHz, is found to show a pronounced peak at 105° C. The anisotropic behavior of this peak is in good agreement with the four-level valence-exchange model proposed by Clogston. The model yields for the electron ordering energy a value 5×10^{-4} eV which agrees closely with the energy deduced from magnetic anneal studies. The activation energy for electron transfer (0.25 eV) is virtually identical with values reported in investigations of electrical conductivity and acoustic loss.

It is known that the introduction of small concentrations of silicon into the YIG lattice leads to a significant increase in magnetic loss. There is general agreement, however, that silicon itself plays only an incidental role and that the losses are actually due to the presence of divalent iron created in response to the addition of quadrivalent silicon.

In YIG samples containing Fe²⁺ two peaks have been reported in the plot of microwave resonance linewidth vs temperature. Typically, one peak occurs at low temperature below ca. 100°K, and the other above ca. 300°K. It was suggested, at the time of its discovery, that the low temperature peak was due to valence exchange,^{1,2} i.e., electron transfer between Fe²⁺ and Fe³⁺ cations. More recently, Tchernev³ has argued that the electron-hopping mechanism is, in all likelihood, "frozen out" at temperatures below 100°K, and therefore, it is more reasonable to ascribe the peak to the localized Fe²⁺ ion acting, more or less,⁴ as a slow relaxer. The high temperature peak has been looked at to a

lesser extent^{5,7} and the suggestion has been made that it is due to valence exchange.⁷

In our work the temperature dependence and anisotropy of the upper peak have been examined in some detail. Our results provide strong evidence that the high temperature resonance losses are, indeed, due to valence exchange, a conclusion that would seem to exclude this mechanism as the one also responsible for the low temperature peak.

We have measured the linewidth of the uniform precession at 13.4 kMHz for several single crystals of silicon-doped YIG (Y₃Fe₅₋₈Si₈O₁₂) between room temperature and the Curie point. The crystals were grown from a PbO-PbF₂ flux using high purity starting materials to which controlled amounts of SiO₂ were added. Silicon concentration was determined from spectrographic analysis of several crystals (not the actual samples) selected from the growth run. Measurements were made on samples prepared as well polished spheres, 0.025" in diameter. These were mounted in a TE-108 transmission cavity and linewidth measurements were made using the half-power method.⁸

Our results for the composition $\delta = 0.06$ are shown in Fig. 1. A sample containing a smaller silicon content ($\delta = 0.04$) showed the same temperature dependence but with the magnitude of the losses reduced roughly in proportion to the doping.

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